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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Details	
Product Status	Obsolete
Core Processor	PIC
Core Size	8-Bit
Speed	4MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, WDT
Number of I/O	13
Program Memory Size	3.5KB (2K x 14)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	2.5V ~ 6V
Data Converters	-
Oscillator Type	External
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	20-SSOP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16lc622-04e-ss

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Device Differences

Device	Device Voltage Range Oscillator		Process Technology (Microns)
PIC16C620 ⁽³⁾	2.5 - 6.0	See Note 1	0.9
PIC16C621 ⁽³⁾	2.5 - 6.0	See Note 1	0.9
PIC16C622 ⁽³⁾	2.5 - 6.0	See Note 1	0.9
PIC16C620A ⁽⁴⁾	2.7 - 5.5	See Note 1	0.7
PIC16CR620A ⁽²⁾	2.5 - 5.5	See Note 1	0.7
PIC16C621A ⁽⁴⁾	2.7 - 5.5	See Note 1	0.7
PIC16C622A ⁽⁴⁾	2.7 - 5.5	See Note 1	0.7

Note 1: If you change from this device to another device, please verify oscillator characteristics in your application.

2: For ROM parts, operation from 2.5V - 3.0V will require the PIC16LCR62X parts.

3: For OTP parts, operation from 2.5V - 3.0V will require the PIC16LC62X parts.

4: For OTP parts, operations from 2.7V - 3.0V will require the PIC16LC62XA parts.

NOTES:

Name	DIP/SOIC Pin #	SSOP Pin #	I/O/P Type	Buffer Type	Description
OSC1/CLKIN	16	18	I	ST/CMOS	Oscillator crystal input/external clock source input.
OSC2/CLKOUT	15	17	0	_	Oscillator crystal output. Connects to crystal or resonator in Crystal Oscillator mode. In RC mode, OSC2 pin out- puts CLKOUT, which has 1/4 the frequency of OSC1 and denotes the instruction cycle rate.
MCLR/VPP	4	4	I/P	ST	Master Clear (Reset) input/programming voltage input. This pin is an Active Low Reset to the device.
					PORTA is a bi-directional I/O port.
RA0/AN0	17	19	I/O	ST	Analog comparator input
RA1/AN1	18	20	I/O	ST	Analog comparator input
RA2/AN2/VREF	1	1	I/O	ST	Analog comparator input or VREF output
RA3/AN3	2	2	I/O	ST	Analog comparator input /output
RA4/T0CKI	3	3	I/O	ST	Can be selected to be the clock input to the Timer timer/counter or a comparator output. Output is open drain type.
					PORTB is a bi-directional I/O port. PORTB can be software programmed for internal weak pull-up on all inputs.
RB0/INT	6	7	I/O	TTL/ST ⁽¹⁾	RB0/INT can also be selected as an externa interrupt pin.
RB1	7	8	I/O	TTL	
RB2	8	9	I/O	TTL	
RB3	9	10	I/O	TTL	
RB4	10	11	I/O	TTL	Interrupt-on-change pin.
RB5	11	12	I/O	TTL	Interrupt-on-change pin.
RB6	12	13	I/O	TTL/ST ⁽²⁾	Interrupt-on-change pin. Serial programming clock
RB7	13	14	I/O	TTL/ST ⁽²⁾	Interrupt-on-change pin. Serial programming data.
Vss	5	5,6	Р		Ground reference for logic and I/O pins.
Vdd	14	15,16	Р	_	Positive supply for logic and I/O pins.
Legend:	O = out — = No	•	I/O = inp I = Input	ut/output	P = power ST = Schmitt Trigger input

TTL = TTL input

Note 1: This buffer is a Schmitt Trigger input when configured as the external interrupt.

2: This buffer is a Schmitt Trigger input when used in Serial Programming mode.

7.0 COMPARATOR MODULE

The comparator module contains two analog comparators. The inputs to the comparators are multiplexed with the RA0 through RA3 pins. The On-Chip Voltage Reference (Section 8.0) can also be an input to the comparators.

The CMCON register, shown in Register 7-1, controls the comparator input and output multiplexers. A block diagram of the comparator is shown in Figure 7-1.

REGISTER 7-1: CMCON REGISTER (ADDRESS 1Fh)

			(,				
	R-0	R-0	U-0	U-0	R/W-0	R/W-0	R/W-0	R/W-0
	C2OUT	C10UT	—	—	CIS	CM2	CM1	CM0
	bit 7							bit 0
bit 7	C2OUT : Co	omparator 2	output					
	1 = C2 VIN	+ > C2 VIN-						
	0 = C2 VIN	+ < C2 VIN-						
bit 6	C1OUT : Co	omparator 1	output					
	1 = C1 VIN	+ > C1 VIN-						
	0 = C1 VIN	+ < C1 VIN-						
bit 5-4	Unimplem	ented: Read	d as '0'					
bit 3	CIS: Comp	arator Input	Switch					
	When CM<	<2:0>: = 001	:					
	1 = C1 VIN-	- connects to	o RA3					
	0 = C1 VIN	- connects to	o RA0					
	When CM<	<2:0> = 010:						
		 connects to 						
		I- connects t						
		- connects to						
	C2 VIN	I- connects t	0 RA1					
bit 2-0	CM<2:0>:	Comparator	mode.					
	Legend:							

Legend:			
R = Readable bit	W = Writable bit	U = Unimplemented	bit, read as '0'
- n = Value at POR	'1' = Bit is set	'0' = Bit is cleared	x = Bit is unknown

9.2 Oscillator Configurations

9.2.1 OSCILLATOR TYPES

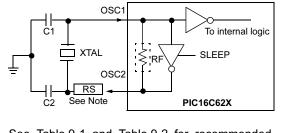
The PIC16C62X devices can be operated in four different oscillator options. The user can program two configuration bits (FOSC1 and FOSC0) to select one of these four modes:

- LP Low Power Crystal
- XT Crystal/Resonator
- HS High Speed Crystal/Resonator
- RC Resistor/Capacitor

9.2.2 CRYSTAL OSCILLATOR / CERAMIC RESONATORS

In XT, LP or HS modes, a crystal or ceramic resonator is connected to the OSC1 and OSC2 pins to establish oscillation (Figure 9-1). The PIC16C62X oscillator design requires the use of a parallel cut crystal. Use of a series cut crystal may give a frequency out of the crystal manufacturers specifications. When in XT, LP or HS modes, the device can have an external clock source to drive the OSC1 pin (Figure 9-2).

FIGURE 9-1: CRYSTAL OPERATION (OR CERAMIC RESONATOR) (HS, XT OR LP OSC CONFIGURATION)



See Table 9-1 and Table 9-2 for recommended values of C1 and C2.

Note: A series resistor may be required for AT strip cut crystals.

FIGURE 9-2: EXTERNAL CLOCK INPUT OPERATION (HS, XT OR LP OSC

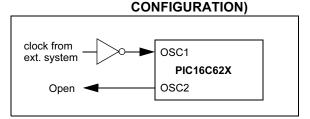


TABLE 9-1:CAPACITOR SELECTION FOR
CERAMIC RESONATORS

R	anges Charao	21				
Mode	Freq	0562(C2)				
ХТ	455 kHz 2.0 MHz 4.0 MHz	22 - 100 pF 15 - 68 pF 15 - 68 pF	82 - 100 pF 15 - 68 pF 15 - 68 pF			
HS	8.0 MHz 16.0 MHz 🔨	10-68 pF 10-22 pF	10 - 68 pF 10 - 22 pF			
Higher capacitance increases the stability of the oscil- lator but also increases the start-up time. These walkes are for design guidance only. Since each resonator has its own characteristics, the user should consult the resonator manufacturer for appropriate values of external components.						

TABLE 9-2: CAPACITOR SELECTION FOR CRYSTAL OSCILLATOR

Mode	Freq	OSC1(C1)	OSC2(C2)		
LP	32 kHz	68 - 100 pF	68 - 100 pF		
	200 kHz	15 - 30 pF	15 - 30 pF		
хт	100 kHz	68 - 150 pF	150-300 pF		
	2 MHz	15 - 30 pF	15-30 pF		
	4 MHz	15 - 30 pF	15-30 pF		
HS	8 MHz	15-30 pF	^V 15 - 30 pF		
	10 MHz	15-30 pF	15 - 30 pF		
	20 MHz 🔨	15-30 pF	15 - 30 pF		
Higher capacitance, increases the stability of the oscillator but also increases the start-up time. These values are for design guidance only. Rs may be required in HS mode as well as XT mode to avoid overdriving crystals with low drive level specification. Since each crystal has its own characteristics, the user should consult the crystal manufacturer for appropriate values of external components.					

9.4 Power-on Reset (POR), Power-up Timer (PWRT), Oscillator Start-up Timer (OST) and Brown-out Reset (BOR)

9.4.1 POWER-ON RESET (POR)

The on-chip POR circuit holds the chip in RESET until VDD has reached a high enough level for proper operation. To take advantage of the POR, just tie the MCLR pin through a resistor to VDD. This will eliminate external RC components usually needed to create Power-on Reset. A maximum rise time for VDD is required. See Electrical Specifications for details.

The POR circuit does not produce an internal RESET when VDD declines.

When the device starts normal operation (exits the RESET condition), device operating parameters (voltage, frequency, temperature, etc.) must be met to ensure operation. If these conditions are not met, the device must be held in RESET until the operating conditions are met.

For additional information, refer to Application Note AN607, "Power-up Trouble Shooting".

9.4.2 POWER-UP TIMER (PWRT)

The Power-up Timer provides a fixed 72 ms (nominal) time-out on power-up only, from POR or Brown-out Reset. The Power-up Timer operates on an internal RC oscillator. The chip is kept in RESET as long as PWRT is active. The PWRT delay allows the VDD to rise to an acceptable level. A configuration bit, PWRTE can disable (if set) or enable (if cleared or programmed) the Power-up Timer. The Power-up Timer should always be enabled when Brown-out Reset is enabled.

The Power-up Time delay will vary from chip-to-chip and due to VDD, temperature and process variation. See DC parameters for details.

9.4.3 OSCILLATOR START-UP TIMER (OST)

The Oscillator Start-Up Timer (OST) provides a 1024 oscillator cycle (from OSC1 input) delay after the PWRT delay is over. This ensures that the crystal oscillator or resonator has started and stabilized.

The OST time-out is invoked only for XT, LP and HS modes and only on Power-on Reset or wake-up from SLEEP.

9.4.4 BROWN-OUT RESET (BOR)

The PIC16C62X members have on-chip Brown-out Reset circuitry. A configuration bit, BODEN, can disable (if clear/programmed) or enable (if set) the Brown-out Reset circuitry. If VDD falls below 4.0V refer to VBOR parameter D005 (VBOR) for greater than parameter (TBOR) in Table 12-5. The brown-out situation will RESET the chip. A RESET won't occur if VDD falls below 4.0V for less than parameter (TBOR).

On any RESET (Power-on, Brown-out, Watchdog, etc.) the chip will remain in RESET until VDD rises above BVDD. The Power-up Timer will now be invoked and will keep the chip in RESET an additional 72 ms.

If VDD drops below BVDD while the Power-up Timer is running, the chip will go back into a Brown-out Reset and the Power-up Timer will be re-initialized. Once VDD rises above BVDD, the Power-Up Timer will execute a 72 ms RESET. The Power-up Timer should always be enabled when Brown-out Reset is enabled. Figure 9-7 shows typical Brown-out situations.

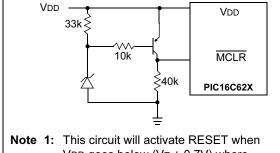


FIGURE 9-7: BROWN-OUT SITUATIONS

FIGURE 9-11: EXTERNAL POWER-ON RESET CIRCUIT (FOR SLOW VDD POWER-UP) Vdd Vdd D R R1 MCLR PIC16C62X С Note 1: External Power-on Reset circuit is required only if VDD power-up slope is too slow. The diode D helps discharge the capacitor quickly when VDD powers down. **2:** < 40 k Ω is recommended to make sure that voltage drop across R does not violate the device's electrical specification. **3:** R1 = 100Ω to 1 k Ω will limit any current flowing into MCLR from external capacitor C in the event of MCLR/VPP pin

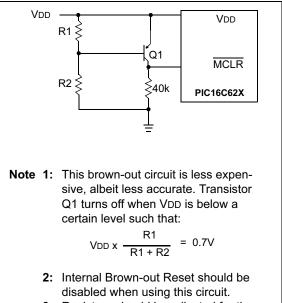
breakdown due to Electrostatic Discharge (ESD) or Electrical Overstress (EOS).

FIGURE 9-12: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 1



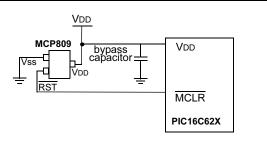
- Note 1: This circuit will activate RESET when VDD goes below (Vz + 0.7V) where Vz = Zener voltage.
 - **2:** Internal Brown-out Reset circuitry should be disabled when using this circuit.

FIGURE 9-13: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 2



3: Resistors should be adjusted for the characteristics of the transistor.

FIGURE 9-14: EXTERNAL BROWN-OUT PROTECTION CIRCUIT 3



This brown-out protection circuit employs Microchip Technology's MCP809 microcontroller supervisor. The MCP8XX and MCP1XX families of supervisors provide push-pull and open collector outputs with both high and low active RESET pins. There are 7 different trip point selections to accommodate 5V and 3V systems.

RLF	Rotate	Left f thr	oua	h Car	rv
Syntax:	[label]	RLF	f,d		
Operands:	0 ≤ f ≤ 1 d ∈ [0,1				
Operation:	See des	scription I	pelov	N	
Status Affected:	С				
Encoding:	00	1101	df	ff	ffff
escription:	rotated the Carr is place		the 'd' is V reg	left th 0, the jister. back	rough e result If 'd' is
Vords:	1				
Cycles:	1				
xample	RLF	REG1,	0		
	Before I After Ins	nstructio REG1 C struction REG1 W	n = = =	1110 0 1110 1100	
		С	=	1	

RRF	Rotate R	ight f th	nroug	gh Ca	arry		
Syntax:	[label]	[<i>label</i>] RRF f,d					
Operands:	$\begin{array}{l} 0 \leq f \leq 127 \\ d \in [0,1] \end{array}$						
Operation:	See desc	ription b	elow	'			
Status Affected:	С						
Encoding:	00	1100	df	ff	ffff		
Description:	The contents of register 'f' are rotated one bit to the right through the Carry Flag. If 'd' is 0, the result is placed in the W register. If 'd' is 1, the result is placed back in register 'f'.						
		; _▶	Regis	ter f	}		
Words:	1						
Cycles:	1						
Example	RRF		REG 0	61,			
	Before In	structior	ı				
		REG1 C	= =	1110 0	0110		
	After Inst						
	1	REG1 W C	= = =	1110 0111 0			

SLEEP

VIII						
Syntax:	[label]	SLEEF	D			
Operands:	None					
Operation:	$\begin{array}{l} 00h \rightarrow WDT, \\ 0 \rightarrow \underline{W}DT \text{ prescaler,} \\ 1 \rightarrow \underline{TO}, \\ 0 \rightarrow \overline{PD} \end{array}$					
Status Affected:	TO, PD					
Encoding:	00	0000	0110	0011		
Description:	The power-down STATUS bit, PD is cleared. Time-out STATUS bit, TO is set. Watch- dog Timer and its prescaler are cleared. The processor is put into SLEEP mode with the oscillator stopped. See Section 9.8 for more details.					
Words:	1					
Cycles:	1					
Example:	SLEEP					

SWAPF	Swap Ni	bbles in	f			
Syntax:	[<i>label</i>] SWAPF f,d					
Operands:	$0 \le f \le 127$ d $\in [0,1]$					
Operation:	(f<3:0>) - (f<7:4>) -		<i>,</i> .			
Status Affected:	None					
Encoding:	00	1110	dfff	ffff		
Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is 0, the result is placed in W register. If 'd' is 1, the result is placed in register 'f'.					
Words:	1					
Cycles:	1					
Example	SWAPF	REG,	0			
	Before In	struction				
		REG1	= (DxA5		
	After Inst	ruction				
		REG1 W		0xA5 0x5A		

TRIS	Load TRIS Register					
Syntax:	[<i>label</i>] TRIS f					
Operands:	$5 \leq f \leq 7$					
Operation:	(W) \rightarrow TRIS register f;					
Status Affected:	None					
Encoding:	00 0000 0110 Offf					
Description:	The instruction is supported for code compatibility with the PIC16C5X products. Since TRIS registers are readable and writable, the user can directly address them.					
Words:	1					
Cycles:	1					
Example						
	To maintain upward compatibil- ity with future PICmicro [®] prod- ucts, do not use this instruction.					

XORLW	Exclusive OR Literal with W
Syntax:	[<i>label</i> XORLW k]
Operands:	$0 \le k \le 255$
Operation:	(W) .XOR. $k \rightarrow (W)$
Status Affected:	Z
Encoding:	11 1010 kkkk kkkk
Description:	The contents of the W register are XOR'ed with the eight bit literal 'k'. The result is placed in the W register.
Words:	1
Cycles:	1
Example:	XORLW 0xAF
	Before Instruction
	W = 0xB5
	After Instruction
	W = 0x1A
XORWF	
	Exclusive OR W with f
Syntax:	[label] XORWF f,d
Syntax:	[<i>label</i>] XORWF f,d $0 \le f \le 127$
Syntax: Operands:	$ \begin{array}{ll} \textit{[label]} & XORWF & f,d \\ 0 \leq f \leq 127 \\ d \in [0,1] \end{array} $
Syntax: Operands: Operation:	$ \begin{array}{ll} \textit{[label]} & \text{XORWF} & \textit{f,d} \\ 0 \leq \textit{f} \leq 127 \\ d \in [0,1] \\ (W) & \text{XOR.} & (\textit{f}) \rightarrow (\textit{dest}) \end{array} $
Syntax: Operands: Operation: Status Affected:	[<i>label</i>] XORWF f,d $0 \le f \le 127$ $d \in [0,1]$ (W) .XOR. (f) \rightarrow (dest) Z
Syntax: Operands: Operation: Status Affected: Encoding:	$\begin{array}{c c} \textit{[label]} & \text{XORWF} & \textit{f,d} \\ 0 \leq \textit{f} \leq 127 \\ d \in [0,1] \\ (W) . \text{XOR.} (\textit{f}) \rightarrow (\text{dest}) \\ \hline Z \\ \hline \hline 00 & 0110 & \text{dfff} & \text{ffff} \\ \hline \text{Exclusive OR the contents of the} \\ W \text{ register with register 'f'. If 'd' is} \\ 0, \text{ the result is stored in the W} \\ \hline \text{register. If 'd' is 1, the result is} \end{array}$
Syntax: Operands: Operation: Status Affected: Encoding: Description:	$\begin{bmatrix} label \end{bmatrix} \text{ XORWF } f,d$ $0 \le f \le 127$ $d \in [0,1]$ (W) .XOR. (f) \rightarrow (dest) Z $\boxed{00 \qquad 0110 \qquad dfff \qquad ffff}$ Exclusive OR the contents of the W register with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'.
Syntax: Operands: Operation: Status Affected: Encoding: Description: Words:	$[label] XORWF f,d$ $0 \le f \le 127$ $d \in [0,1]$ (W) .XOR. (f) \rightarrow (dest) Z $\boxed{00 0110 dfff ffff}$ Exclusive OR the contents of the W register with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'. 1
Syntax: Operands: Operation: Status Affected: Encoding: Description: Words: Cycles:	[<i>label</i>] XORWF f,d $0 \le f \le 127$ $d \in [0,1]$ (W) .XOR. (f) \rightarrow (dest) Z 00 0110 dfff ffff Exclusive OR the contents of the W register with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'. 1 1
Syntax: Operands: Operation: Status Affected: Encoding: Description: Words: Cycles:	$\begin{bmatrix} label \end{bmatrix} \text{ XORWF } f,d \\ 0 \le f \le 127 \\ d \in [0,1] \\ (W) .XOR. (f) \rightarrow (dest) \\ Z \\ \hline 00 & 0110 & dfff & ffff \\ Exclusive OR the contents of the W register with register 'f'. If 'd' is 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'. \\ 1 \\ 1 \\ XORWF REG 1 \\ \end{bmatrix}$
Syntax: Operands: Operation: Status Affected: Encoding: Description: Words: Cycles:	$\begin{bmatrix} label \end{bmatrix} \text{ XORWF } f,d \\ 0 \le f \le 127 \\ d \in [0,1] \\ (W) .XOR. (f) \rightarrow (dest) \\ Z \\ \hline 00 & 0110 & dfff & ffff \\ \hline Exclusive OR the contents of the \\ W register with register 'f'. If 'd' is \\ 0, the result is stored in the W register. If 'd' is 1, the result is stored back in register 'f'. \\ 1 \\ 1 \\ XORWF & REG & 1 \\ \hline Before Instruction \\ REG & = 0xAF \\ \end{bmatrix}$
Syntax: Operands: Operation: Status Affected: Encoding: Description: Words: Cycles:	$\begin{bmatrix} label \end{bmatrix} \text{ XORWF} f,d \\ 0 \leq f \leq 127 \\ d \in [0,1] \\ (W) .XOR. (f) \rightarrow (dest) \\ Z \\ \hline 00 & 0110 & dfff & ffff \\ \hline Exclusive OR the contents of the \\ W register with register 'f'. If 'd' is \\ 0, the result is stored in the W \\ register. If 'd' is 1, the result is \\ stored back in register 'f'. \\ 1 \\ 1 \\ XORWF & REG & 1 \\ \hline Before Instruction \\ \hline REG &= 0xAF \\ W &= 0xB5 \\ \end{bmatrix}$

NOTES:

11.14 PICDEM 1 PICmicro Demonstration Board

The PICDEM 1 demonstration board demonstrates the capabilities of the PIC16C5X (PIC16C54 to PIC16C58A), PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The sample microcontrollers provided with the PICDEM 1 demonstration board can be programmed with a PRO MATE II device programmer, or a PICSTART Plus development programmer. The PICDEM 1 demonstration board can be connected to the MPLAB ICE in-circuit emulator for testing. A prototype area extends the circuitry for additional application components. Features include analog input, push button switches and eight LEDs.

11.15 PICDEM.net Internet/Ethernet Demonstration Board

The PICDEM.net demonstration board is an Internet/ Ethernet demonstration board using the PIC18F452 microcontroller and TCP/IP firmware. The board supports any 40-pin DIP device that conforms to the standard pinout used by the PIC16F877 or PIC18C452. This kit features a user friendly TCP/IP stack, web server with HTML, a 24L256 Serial EEPROM for Xmodem download to web pages into Serial EEPROM, ICSP/MPLAB ICD 2 interface connector, an Ethernet interface, RS-232 interface, and a 16 x 2 LCD display. Also included is the book and CD-ROM *"TCP/IP Lean, Web Servers for Embedded Systems,"* by Jeremy Bentham

11.16 PICDEM 2 Plus Demonstration Board

The PICDEM 2 Plus demonstration board supports many 18-, 28-, and 40-pin microcontrollers, including PIC16F87X and PIC18FXX2 devices. All the necessary hardware and software is included to run the demonstration programs. The sample microcontrollers provided with the PICDEM 2 demonstration board can be programmed with a PRO MATE II device programmer, PICSTART Plus development programmer, or MPLAB ICD 2 with a Universal Programmer Adapter. The MPLAB ICD 2 and MPLAB ICE in-circuit emulators may also be used with the PICDEM 2 demonstration board to test firmware. A prototype area extends the circuitry for additional application components. Some of the features include an RS-232 interface, a 2 x 16 LCD display, a piezo speaker, an on-board temperature sensor, four LEDs, and sample PIC18F452 and PIC16F877 FLASH microcontrollers.

11.17 PICDEM 3 PIC16C92X Demonstration Board

The PICDEM 3 demonstration board supports the PIC16C923 and PIC16C924 in the PLCC package. All the necessary hardware and software is included to run the demonstration programs.

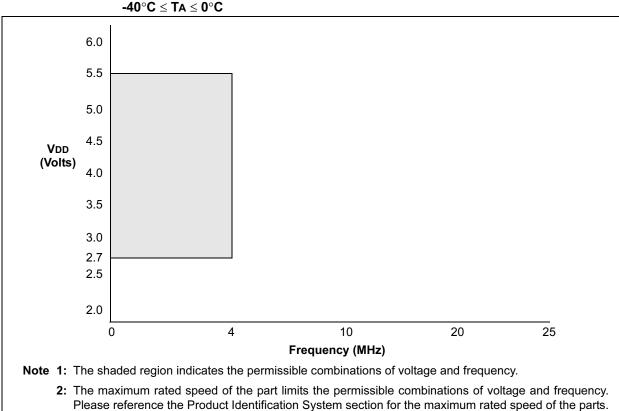
11.18 PICDEM 4 8/14/18-Pin Demonstration Board

The PICDEM 4 can be used to demonstrate the capabilities of the 8-, 14-, and 18-pin PIC16XXXX and PIC18XXXX MCUs, including the PIC16F818/819, PIC16F87/88, PIC16F62XA and the PIC18F1320 family of microcontrollers. PICDEM 4 is intended to showcase the many features of these low pin count parts, including LIN and Motor Control using ECCP. Special provisions are made for low power operation with the supercapacitor circuit, and jumpers allow onboard hardware to be disabled to eliminate current draw in this mode. Included on the demo board are provisions for Crystal, RC or Canned Oscillator modes, a five volt regulator for use with a nine volt wall adapter or battery, DB-9 RS-232 interface, ICD connector for programming via ICSP and development with MPLAB ICD 2, 2x16 liquid crystal display, PCB footprints for H-Bridge motor driver, LIN transceiver and EEPROM. Also included are: header for expansion, eight LEDs, four potentiometers, three push buttons and a prototyping area. Included with the kit is a PIC16F627A and a PIC18F1320. Tutorial firmware is included along with the User's Guide.

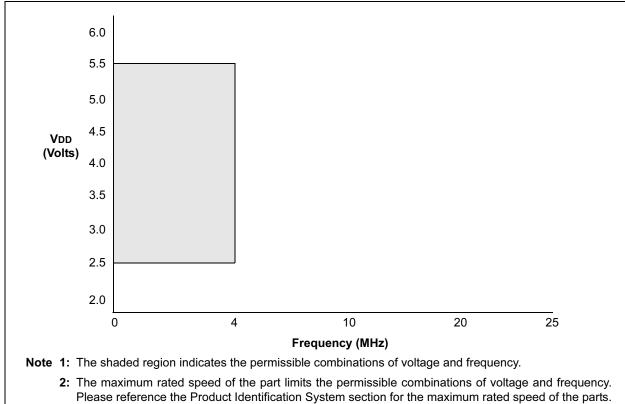
11.19 PICDEM 17 Demonstration Board

The PICDEM 17 demonstration board is an evaluation board that demonstrates the capabilities of several Microchip microcontrollers, including PIC17C752, PIC17C756A, PIC17C762 and PIC17C766. A programmed sample is included. The PRO MATE II device programmer, or the PICSTART Plus development programmer, can be used to reprogram the device for user tailored application development. The PICDEM 17 demonstration board supports program download and execution from external on-board FLASH memory. A generous prototype area is available for user hardware expansion.









12.1 DC Characteristics: PIC16C62X-04 (Commercial, Industrial, Extended) PIC16C62X-20 (Commercial, Industrial, Extended) PIC16LC62X-04 (Commercial, Industrial, Extended)

PIC16C62X Standard Operating Conditions (unless otherwis Operating temperature -40°C ≤ TA ≤ +85°C for ind 0°C ≤ TA ≤ +70°C for con -40°C ≤ TA ≤ +125°C for ex Standard Operating Conditions (unless otherwise)	dustrial and mmercial and
$\begin{array}{c} \mbox{PIC16LC62X} \\ \mbox{PIC16LC62X} \\ \mbox{Operating temperature} & -40^{\circ} C & \leq TA \leq +85^{\circ} C \mbox{ for ind} \\ & 0^{\circ} C & \leq TA \leq +70^{\circ} C \mbox{ for out} \\ & -40^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & \leq TA \leq +125^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & = 0^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & = 0^{\circ} C \mbox{ for expansion} \\ & 0^{\circ} C & = 0^{\circ} C \mbox{ for expansion} \\ & 0^{\circ$	dustrial and mmercial and extended
Param. Sym Characteristic Min Typ† Max Units Conditio No. Conditio	ns
D001 VDD Supply Voltage 3.0 — 6.0 V See Figures 12-1, 12-2, 12-3	3, 12-4, and 12-5
D001 VDD Supply Voltage 2.5 — 6.0 V See Figures 12-1, 12-2, 12-3	3, 12-4, and 12-5
D002 VDR RAM Data Retention Voltage ⁽¹⁾ — 1.5* — V Device in SLEEP mode	
D002 VDR RAM Data Retention Voltage ⁽¹⁾ — 1.5* — V Device in SLEEP mode	
D003 VPOR VDD start voltage to ensure — Vss — V See section on Power-on Report	eset for details
D003 VPOR VDD start voltage to ensure Power-on Reset — Vss — V See section on Power-on Reset	eset for details
D004 SVDD VDD rise rate to ensure 0.05* — — V/ms See section on Power-on Reset	eset for details
D004 SVDD VDD rise rate to ensure 0.05* — — V/ms See section on Power-on Reset	eset for details
D005 VBOR Brown-out Detect Voltage 3.7 4.0 4.3 V BOREN configuration bit is c	cleared
D005 VBOR Brown-out Detect Voltage 3.7 4.0 4.3 V BOREN configuration bit is c	cleared
D010 IDD Supply Current ⁽²⁾ - 1.8 3.3 mA Fosc = 4 MHz, VDD = 5.5V, mode, (Note 4)*	
$ \begin{array}{c c c c c c c c c } \hline & & & \\ \hline & & \\ \hline & & & \\ \hline \hline & & & \\ \hline \\ \hline$	WD1 disabled, LP
9.0 20 mA Fosc = 20 MHz, VDD = 5.5V mode	, WDT disabled, HS
D010 IDD Supply Current ⁽²⁾ — 1.4 2.5 mA Fosc = 2.0 MHz, VDD = 3.0 V	/, WDT disabled, XT
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	WDT disabled, LP
D020 IPD Power-down Current ⁽³⁾ — 1.0 2.5 μ A VDD=4.0V, WDT disabled (125°C)	
D020 IPD Power-down Current ⁽³⁾ — 0.7 2 μ A VDD=3.0V, WDT disabled	

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.

The test conditions for all IDD measurements in Active Operation mode are:

OSC1 = external square wave, from rail to rail; all I/O pins tri-stated, pulled to VDD,

 \overline{MCLR} = VDD; WDT enabled/disabled as specified.

3: The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or Vss.

4: For RC osc configuration, current through REXT is not included. The current through the resistor can be estimated by the formula: Ir = VDD/2REXT (mA) with REXT in kΩ.

5: The Δ current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

12.2 DC Characteristics: PIC16C62XA-04 (Commercial, Industrial, Extended) PIC16C62XA-20 (Commercial, Industrial, Extended) PIC16LC62XA-04 (Commercial, Industrial, Extended (CONT.)

PIC16C62XA				ating te	mpera	ature -4 -4	ditions (unless otherwise stated) $40^{\circ}C \leq TA \leq +85^{\circ}C$ for industrial and $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial and $40^{\circ}C \leq TA \leq +125^{\circ}C$ for extended			
PIC16LC62XA						ature -4	$\begin{array}{ll} \mbox{ditions (unless otherwise stated)} \\ \mbox{H} 0^{\circ} C &\leq T A \leq +85^{\circ} C \mbox{ for industrial and} \\ \mbox{0}^{\circ} C &\leq T A \leq +70^{\circ} C \mbox{ for commercial and} \\ \mbox{0}^{\circ} C &\leq T A \leq +125^{\circ} C \mbox{ for extended} \end{array}$			
Param. No.	Sym	Characteristic	Min	Тур†	Max	Units	Conditions			
D022	ΔIWDT	WDT Current ⁽⁵⁾	—	6.0	10 12	μA μA	VDD = 4.0V (125°C)			
D022A D023	Δ IBOR Δ ICOMP	Brown-out Reset Current ⁽⁵⁾ Comparator Current for each Comparator ⁽⁵⁾	_	75 30	125 60	μA μA	BOD enabled, VDD = 5.0V VDD = 4.0V			
D023A	$\Delta I V REF$	VREF Current ⁽⁵⁾	—	80	135	μA	VDD = 4.0V			
D022 D022A D023	ΔIWDT ΔIBOR ΔICOMP	WDT Current ⁽⁵⁾ Brown-out Reset Current ⁽⁵⁾ Comparator Current for each Comparator ⁽⁵⁾		6.0 75 30	10 12 125 60	μΑ μΑ μΑ	VDD=4.0V (125°C) BOD enabled, VDD = 5.0V VDD = 4.0V			
D023A	Δ IVREF	VREF Current ⁽⁵⁾	_	80	135	μA	VDD = 4.0V			
1A	Fosc	LP Oscillator Operating Frequency RC Oscillator Operating Frequency XT Oscillator Operating Frequency HS Oscillator Operating Frequency	0 0 0 0		200 4 4 20	kHz MHz MHz MHz	All temperatures All temperatures All temperatures All temperatures			
1A	Fosc	LP Oscillator Operating Frequency RC Oscillator Operating Frequency XT Oscillator Operating Frequency HS Oscillator Operating Frequency	0 0 0 0		200 4 4 20	kHz MHz MHz MHz	All temperatures All temperatures All temperatures All temperatures			

These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.

The test conditions for all IDD measurements in Active Operation mode are:

OSC1 = external square wave, from rail to rail; all I/O pins tri-stated, pulled to VDD,

 $\overline{\text{MCLR}}$ = VDD; WDT enabled/disabled as specified.

3: The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in hi-impedance state and tied to VDD or VSS.

4: For RC osc configuration, current through REXT is not included. The current through the resistor can be estimated by the formula: Ir = VDD/2REXT (mA) with REXT in kΩ.

5: The Δ current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

6: Commercial temperature range only.

12.4 DC Characteristics: PIC16C62X/C62XA/CR62XA (Commercial, Industrial, Extended) PIC16LC62X/LC62XA/LCR62XA (Commercial, Industrial, Extended)

PIC16C	62XA/CR62XA	Standard Operating Conditions (unless otherwise stated)Operating temperature -40° C \leq TA \leq +85°C for industrial and 0° C \leq TA \leq +70°C for commercial and							
					-40°C				
PIC16LC62X/LC62XA/LCR62XA									
Param. No.	Sym	Characteristic	Min	Тур†	Мах	Units	Conditions		
	VIL	Input Low Voltage							
		I/O ports							
D030		with TTL buffer	Vss	—	0.8V 0.15 Vdd	V	VDD = 4.5V to 5.5V otherwise		
D031		with Schmitt Trigger input	Vss	—	0.2 VDD	V			
D032		MCLR, RA4/T0CKI,OSC1 (in RC mode)	Vss	—	0.2 VDD	V	(Note 1)		
D033		OSC1 (in XT and HS)	Vss	_	0.3 VDD	V			
		OSC1 (in LP)	Vss	—	0.6 Vdd- 1.0	V			
	VIL	Input Low Voltage							
		I/O ports							
D030		with TTL buffer	Vss	-	0.8V 0.15 VDD	V	VDD = 4.5V to 5.5V otherwise		
D031		with Schmitt Trigger input	Vss	—	0.2 VDD	V			
D032		MCLR, RA4/T0CKI,OSC1 (in RC mode)	Vss	—	0.2 VDD	V	(Note 1)		
D033		OSC1 (in XT and HS)	Vss	—	0.3 VDD	V			
		OSC1 (in LP)	Vss	—	0.6 Vdd- 1.0	V			
	VIH	Input High Voltage							
		I/O ports							
D040		with TTL buffer	2.0V 0.25 VDD + 0.8V	_	Vdd Vdd	V	V _{DD} = 4.5V to 5.5V otherwise		
D041		with Schmitt Trigger input	0.8 Vdd	_	VDD				
D042		MCLR RA4/T0CKI	0.8 VDD	_	VDD	V			
D043 D043A		OSC1 (XT, HS and LP) OSC1 (in RC mode)	0.7 Vdd 0.9 Vdd	_	VDD	V	(Note 1)		

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: In RC oscillator configuration, the OSC1 pin is a Schmitt Trigger input. It is not recommended that the PIC16C62X(A) be driven with external clock in RC mode.

2: The leakage current on the MCLR pin is strongly dependent on applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.

3: Negative current is defined as coming out of the pin.

12.5 DC CHARACTERISTICS: PIC16C620A/C621A/C622A-40⁽⁷⁾ (Commercial) PIC16CR620A-40⁽⁷⁾ (Commercial)

DC CH	IARAC	TERISTICS	Standard Operating Conditions (unless otherwise stated)Operating temperature $0^{\circ}C \leq TA \leq +70^{\circ}C$ for commercial						
Param No.	Sym	Characteristic	Min	Тур†	Мах	Unit	Conditions		
	VIL	Input Low Voltage							
		I/O ports							
D030		with TTL buffer	Vss	_	0.8V 0.15Vdd	V	VDD = 4.5V to 5.5V, otherwise		
D031		with Schmitt Trigger input	Vss		0.2VDD	V			
D032		MCLR, RA4/T0CKI, OSC1 (in RC mode)	Vss	—	0.2Vdd	V	(Note 1)		
D033		OSC1 (in XT and HS)	Vss	_	0.3VDD	V			
		OSC1 (in LP)	Vss	_	0.6Vdd - 1.0	V			
	Vih	Input High Voltage							
		I/O ports							
D040		with TTL buffer	2.0V	—	Vdd	V	VDD = 4.5V to 5.5V, otherwise		
			0.25 VDD + 0.8		Vdd				
D041		with Schmitt Trigger input	0.8 VDD		Vdd				
D042		MCLR RA4/T0CKI	0.8 VDD	—	Vdd	V			
D043		OSC1 (XT, HS and LP)	0.7 Vdd	—	Vdd	V			
D043A		OSC1 (in RC mode)	0.9 VDD				(Note 1)		
D070	IPURB	PORTB Weak Pull-up Current	50	200	400	μA	VDD = 5.0V, VPIN = VSS		
	lı∟	Input Leakage Current ^(2, 3)							
		I/O ports (except PORTA)			±1.0	μA	Vss \leq VPIN \leq VDD, pin at hi-impedance		
D060		PORTA	—	—	±0.5	μA	Vss \leq VPIN \leq VDD, pin at hi-impedance		
D061		RA4/T0CKI	—	_	±1.0	μA	$Vss \le VPIN \le VDD$		
D063		OSC1, MCLR	_	—	±5.0	μA	Vss \leq VPIN \leq VDD, XT, HS and LP osc configuration		
	Vol	Output Low Voltage							
D080		I/O ports	_	_	0.6	V	IOL = 8.5 mA, VDD = 4.5V, -40° to +85°C		
			_	—	0.6	V	IOL = 7.0 mA, VDD = 4.5V, +125°C		
D083		OSC2/CLKOUT (RC only)	_	—	0.6	V	IOL = 1.6 mA, VDD = 4.5V, -40° to +85°C		
					0.6	V	IOL = 1.2 mA, VDD = 4.5V, +125°C		
	Vон	Output High Voltage ⁽³⁾							
D090		I/O ports (except RA4)	VDD-0.7	—	—	V	IOH = -3.0 mA, VDD = 4.5V, -40° to +85°C		
			VDD-0.7	_	—	V	ІОН = -2.5 mA, VDD = 4.5V, +125°C		
D092		OSC2/CLKOUT (RC only)	VDD-0.7	_	—	V	IOH = -1.3 mA, VDD = 4.5V, -40° to +85°C		
			VDD-0.7	-	—	V	Іон = -1.0 mA, Vdd = 4.5V, +125°C		
*D150	Vod	Open Drain High Voltage			8.5	V	RA4 pin		
		Capacitive Loading Specs on Output Pins							
D100	Cosc2	OSC2 pin			15	pF	In XT, HS and LP modes when external clock used to drive OSC1.		
D101	Cio	All I/O pins/OSC2 (in RC mode)			50	pF			
		parameters are characterized but not	<u> </u>	1	~~	۳.			

* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C, unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.

2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as I/O pin loading and switching rate, oscillator type, internal code execution pattern, and temperature also have an impact on the current consumption.

The test conditions for all IDD measurements in Active Operation mode are:

OSC1 = external square wave, from rail-to-rail; all I/O pins tri-stated, pulled to VDD, MCLR = VDD; WDT enabled/disabled as specified.
 The power-down current in SLEEP mode does not depend on the oscillator type. Power-down current is measured with the part in SLEEP mode, with all I/O pins in bi-impedance state and tied to VDD or VSS.

mode, with all I/O pins in hi-impedance state and tied to VDD or VSs.
For RC osc configuration, current through REXT is not included. The current through the resistor can be estimated by the formula Ir = VDD/ 2REXT (mA) with REXT in kΩ.

5: The Δ current is the additional current consumed when this peripheral is enabled. This current should be added to the base IDD or IPD measurement.

6: Commercial temperature range only.

7: See Section 12.1 and Section 12.3 for 16C62X and 16CR62X devices for operation between 20 MHz and 40 MHz for valid modified characteristics.

12.8 Timing Parameter Symbology

The timing parameter symbols have been created with one of the following formats:

1. TppS2ppS

2. TppS

2. Tpp3			
т			
F	Frequency	Т	Time
Lowerca	ase subscripts (pp) and their meanings:		
рр			
ck	CLKOUT	osc	OSC1
io	I/O port	t0	ТОСКІ
mc	MCLR		
Upperca	ase letters and their meanings:		
S			
F	Fall	Р	Period
Н	High	R	Rise
I	Invalid (Hi-impedance)	V	Valid
L	Low	Z	Hi-Impedance

FIGURE 12-11: LOAD CONDITIONS

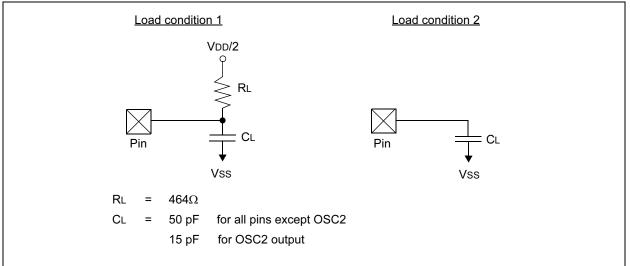


FIGURE 12-16: TIMER0 CLOCK TIMING

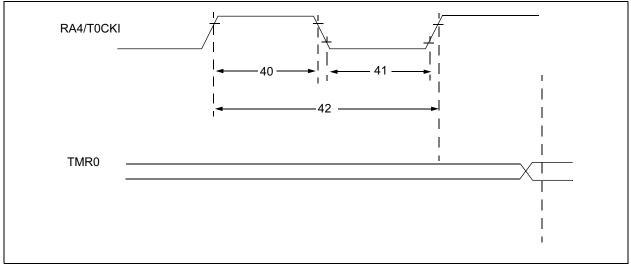
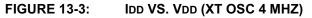


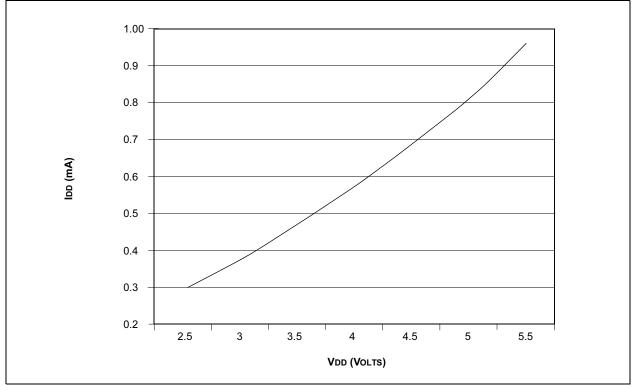
TABLE 12-6:	TIMER0 CLOCK REQUIREMENTS
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Parameter No.	Sym	Characteristic		Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High Pulse Width	No Prescaler	0.5 Tcy + 20*	—	_	ns	
			With Prescaler	10*	—	—	ns	
41	Tt0L	T0CKI Low Pulse Width	No Prescaler	0.5 Tcy + 20*	—	_	ns	
			With Prescaler	10*	—	_	ns	
42	Tt0P	T0CKI Period		<u>Tcy + 40</u> * N	_	_	ns	N = prescale value (1, 2, 4,, 256)

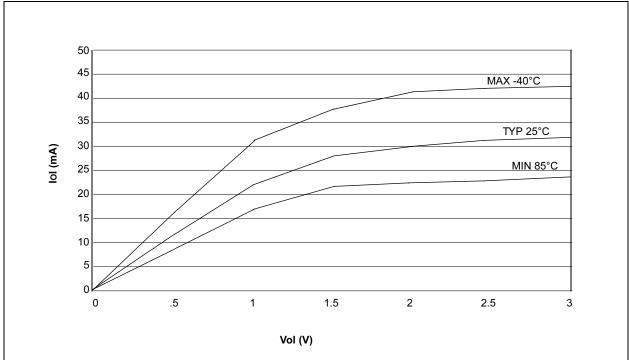
* These parameters are characterized but not tested.

† Data in "Typ" column is at 5.0V, 25°C, unless otherwise stated. These parameters are for design guidance only and are not tested.









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